



**UNIVERSITI PUTRA MALAYSIA**

***CHARACTERIZATION OF  $Zn_xCd_{1-x}S$  TERNARY SEMICONDUCTOR  
NANOPARTICLES SYNTHESIZED BY MICROWAVE-ASSISTED  
HYDROTHERMAL TECHNIQUE***

**MINA ASKARI VERNOSFADERANI**

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HYDROTHERMAL TECHNIQUE**

By

**MINA ASKARI VERNOSFADERANI**

**This Thesis Submitted to the School of Graduate Studies, Universiti Putra Malaysia,  
in Fulfillment of the Requirements for the Degree of Master of Science**

**July 2014**

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## DEDICATION

*I lovingly dedicate this thesis to my husband, Mahdi, who supported me  
each step of the way and remains willing to engage with the struggle,*

*My dear family, for being so supportive,*

*and my sweetheart daughter Gisu*



Abstract of thesis presented to the Senate of Universiti Putra Malaysia in fulfilment  
of the requirement for the degree of Master of Science

# CHARACTERIZATION OF $Zn_xCd_{1-x}S$ TERNARY SEMICONDUCTOR NANOPARTICLES SYNTHESIZED BY MICROWAVE-ASSISTED HYDROTHERMAL TECHNIQUE

By

**MINA ASKARI VERNOSFADERANI**

**July 2014**

**Chairman: Professor Elias Saion, PhD**

**Faculty: Science**

In this work, the microwave-assisted hydrothermal method was used to synthesize  $Zn_xCd_{1-x}S$  ternary quantum dots. In order to study the effect of different stoichiometries on  $Zn_xCd_{1-x}S$  properties, the molar ratio of Zn/Cd was chosen as 0.1/0.9, 0.3/0.7, 0.5/0.5, 0.7/0.3, and 0.9/0.1, and to use semiconductor quantum dots in technology, the stability of these materials is very important and can be achieved by capping the particles with either organic or inorganic materials like polymers. Zinc chloride ( $ZnCl_2$ ), cadmium chloride ( $CdCl_2$ ), and sodium sulfide ( $Na_2S$ ) were used as Zn, Cd, and S sources respectively, and polyvinylpyrrolidone (PVP) and thioglycolic acid (TGA) were used as capping agent and stabilizer to control particle's growth and distilled water as a solvent. The solution was heated in a microwave oven with 100% power for 4 minutes and the resulting precipitation was centrifuged, washed, and dried at 100 °C for 24 hours. By increasing the value of x from 0.1 to x=0.9, the powder color changed from dark yellow to white as verified by X-ray diffraction (XRD). The average particle sizes of  $Zn_xCd_{1-x}S$  nanoparticles as deduced from Sherrer's equation by XRD peaks and from the images of transmission electron microscopy (TEM) were found to vary within range 3-5 nm with x values. The optical band gap energy in the range of 2.3 to 2.93 eV was calculated by Tauc plot of the UV-visible spectra. The band gap has increased with increasing the value of x due to a decrease in particle size.

The synthesized  $Zn_{0.9}Cd_{0.1}S$  quantum dots capped by TGA and PVP have band gaps between 2.93 to 3.43, and 2.91 to 2.98 eV respectively. PL spectra for  $Zn_xCd_{1-x}S$  have three emission peaks related to sulfur, zinc, and cadmium vacancies respectively. The emission peaks II that belong to zinc vacancies are observed at 484, 483, 483, 481, and 478 nm that are shifted to the lower wavelengths by increasing the value of x, and correspond to 2.56, 2.57, 2.57, 2.58, and 2.6 eV. This significant continuous shift is an evidence for the formation of the ternary  $Zn_xCd_{1-x}S$  quantum dot, rather than forming separate CdS, ZnS, or core-shell nanoparticle structure.

Abstrak tesis yang dikemukakan kepada Senat Universiti Putra Malaysia  
Sebagai memenuhi keperluan untuk ijazah Master Sains

**PENCIRIAN  $Zn_xCd_{1-x}S$  TERNARY SEMIKONDUKTOR NANOPARTIKEL  
DISINTESIS OLEH MIKROWAVE-DIBANTU HIDROTERMA TEKNIK**

Oleh

**MINA ASKARI VERNOSFADERANI**

**Julai 2014**

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Dalam karya ini, kaedah hidroterma dibantu ketuhar gelombang mikro telah digunakan untuk mensintesis titik kuantum, nanopartikel ternary  $Zn_xCd_{1-x}S$ , ( $x = 0.1, 0.3, 0.5, 0.7$  dan  $0.9$ ). Zink klorida ( $ZnCl_2$ ), kadmium klorida ( $CdCl_2$ ) dan natrium sulfida ( $Na_2S$ ) telah digunakan sebagai sumber, Zn, Cd dan S masing-masing dan polyvinylpyrrolidone (PVP) dan asid thioglycolic (TGA) digunakan sebagai ejen menutup dan penstabil kepada pertumbuhan nanopartikel secara terkawal dan air suling sebagai pelarut. Larutan dipanaskan di dalam ketuhar gelombang mikro dengan kuasa 100% selama 4 minit dan mendakan yang terhasil mengalami emparan, dibasuh dan dikeringkan pada  $100^\circ C$  selama 24 jam. Dengan meningkatkan nilai  $x$  daripada 0.1 untuk  $x = 0.9$ , warna serbuk bertukar daripada kuning gelap kepada putih dan keristiliti zarah ditukar daripada struktur hexagon kepada struktur kubus seperti yang disahkan oleh belauan sinar-x (XRD). Saiz purata nanopartikel  $Zn_xCd_{1-x}S$  seperti yang ditentukan dari persamaan Sherrer oleh puncak XRD dan imej-imej transmisi elektron microscopy (Julai) didapati berada dalam julat 3-5 nm dengan pertambahan nilai  $x$ . Jurang jalur tenaga optik telah dikira dengan plot Tauc untuk cahaya UV-tampak. Jurang tenaga telah meningkat dengan peningkatan nilai  $x$  antara 2.75 dan 3.02 (eV). Sintesis  $Zn_xCd_{1-x}S$  dengan TGA dan PVP mendapati jurang tenaga antara 2.98 hingga 3.04 eV dan 2.90 hingga 3.21 masing-masing. Spektrum PL untuk  $Zn_xCd_{1-x}S$  mempunyai tiga puncak penyinaran yang berkaitan dengan sulfur, zink dan kadmium masing-masing. Puncak penyinaran II dipunyai untuk zink yang dapat dilihat di 484, 483, 483, 481, dan 478 yang akan berpindah ke gelombang lebih rendah dengan meningkatkan nilai  $x$ , dan sesuai dengan nilai 2.56, 2.57, 2.57, 2.58 dan 2.6 (eV) masing-masing.



This thesis was submitted to the Senate of Universiti Putra Malaysia and has been accepted as fulfilment of the requirement for the degree of Master of science. The members of the Supervisory Committee were as follows:

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## LIST OF ABBREVIATIONS

CdCl <sub>2</sub>	Cadmium chloride
LED	Light-emitting diode
Na <sub>2</sub> S	Sodium sulfide
PL	Photoluminescence
PVP	Polyvinylpyrrolidone
QD	Quantum dot
TEM	transmission electron microscope
TGA	Thioglycolic acid
UV-Vis	Ultraviolet-Visible light spectroscopy
XRD	X-ray diffraction
ZnCl <sub>2</sub>	Zinc chloride

## LIST OF SYMBOLS

A	Absorbance
$C_p$	Specific heat capacity
$C_s$	Saturated concentration of the ions in the solution
$C_{ss}$	Supersaturated concentration of the ions in the solution
$E_a$	Activation energy
$E_c$	Energy of conduction band
$E_g$	Energy of band gap
$E_v$	Energy of valence band
$E_{rms}^2$	Root mean square of the internal electric field
F	Frequency
$G_{l \rightarrow s}$	Free energy change per unit volume when new nuclei are formed from a liquid
$I_0$	Incident light
$I(z)$	Flux density
J	Current density
K	Rate constant of chemical reaction
M	Rest mass of electron
$M^*$	Mass of the particle
R	Gas constant
T	Absolute temperature
$T_b$	Bulk temperature
$T_i$	Instantaneous temperature
Z	Distance
$\alpha_0$	Bohr's radius of hydrogen atom

$\alpha(z)$	Absorbtion coefficient
$\beta$	Line boardening at half maximum intensity
$\gamma$	Specific surface energy of the nucleus
$\varepsilon$	Dielectric constant
$\varepsilon_0$	Dielectric permittivity of free space
$\check{\varepsilon}_{\text{eff}}$	Effective relative dielectric loss factor
$\theta$	Bragg angle
$\kappa$	Boltzman's constant
$\lambda_0$	Wavelength of microwave
$v_s$	Volume per molecule in the solid
$\rho$	Density
$\sigma$	Electrical conductivity
$\Phi$	Work function

## CHAPTER 1

### INTRODUCTION

#### 1.1 Background of study

Nanoscience is a wide study area pertaining to diverse methods of synthesis and characterization of nanomaterials such as metal nanoparticles and semiconductor quantum dots- which is a type of nanocrystal made of semiconductor materials that are small enough to exhibit quantum mechanical properties- leading to their high potential applications in medicine, cancer therapy, optical devices, catalysis, and solar cell. Because of their particle size varies in range 1- 100 nm, their electronic parameters are size dependent such that they are promising candidates for optical devices. These types of materials have different electronic and optical properties compared to their bulk material counterparts. Their expanded surface leads to a new atomic arrangement which has an effect on optical properties of nanoparticles. The high surface to volume ratio can cause an increase in surface specific active sites for chemical reactions and photon absorption to enhance reaction and absorption efficiency, and an increase in the surface states, which changes the activity of electrons and holes and affects the chemical reaction dynamics. By decreasing the size of particles, the confinement charge carriers and the quantum size effect can occur, both conduction and valence band can split into discrete electronic states, and the band gap and optical and electronic properties become size dependence.

Ternary chalcogenide-based semiconductor quantum dots have unique size-tunable, optical, and electronic properties. These semiconducting materials have a broad range of applications in photovoltaic devices and solar cells. The Zinc Cadmium Sulfide (ZnCdS) ternary quantum dot is promising candidate as blue emitter and wide bandgap window material in photoconductive devices and heterojunction solar cells.

Among the expand range of nanomaterials, the  $Zn_xCd_{1-x}S$  semiconductor quantum dots (QDs) are the best wide band gap window materials due to its tunable size, shape, and emitting color. To control the shape and size of corresponding QDs many different synthesis methods are presented such as gas-phase process, microwave-assisted hydrothermal method, co-precipitation method, chemical bath deposition, and solvothermal method. The hydrothermal method is useful for the growth of crystals with the ability of good control of their composition. Methods of synthesis the nanoparticles are expected to modify the nanoparticle's surface and properties and form them with narrow size distribution.

#### 1.2 Problem statement

Semiconductor nanoparticles have an important role in new world due to their wide range of applications such as optical devices. In order to use them in technology, their particle size, size distribution, morphology, and optical properties are necessary to be controlled. Recent studies improve the way of synthesis nanoparticles and

introduce some solution to control their properties during the formation process. The optical properties of semiconductor quantum dots are affected by their size distribution and surface that should be controlled to achieve desired optical characters. Some of the synthesis methods cause the large size and unstable particles or require longer hours to complete. Furthermore the products may result in amorphous phase, poor dispersion and with impurities. The microwave-assisted method and capping the nanoparticles with some materials as stabilizer can overcome these problems and give the semiconductor quantum dots with desired properties. In order to use semiconductor nanoparticles in technology, the stability of these materials is very important and can achieve by capping the particles with either organic or inorganic materials like polymers. The utilization of capping agents in nanoparticles synthesis is a way to provide chemical passivation, and improve the surface state that has a significant effect on the optical and electronic properties of nanoparticles. They prevent agglomeration of the nanoparticles and boost their optical properties and stability.

### 1.3 Study objective

In the terms of knowledge creation, this work includes fundamental research of semiconductor QDs synthesis process, effect of precursor's concentration, and also capping agents on physical and optical properties of nanoparticles. In details, in this project the high quality  $Zn_xCd_{1-x}S$  semiconductor ternary QDs were synthesized via microwave irradiation with x values of 0.1, 0.3, 0.5, 0.7, and 0.9, and two types of capping agents with concentration from 1% to 5% and characterized to find their properties. To activate successful achievement of these, the thesis research is divided into the following particular objectives:

- 1- To synthesize high purity and quality ZnCdS semiconductor ternary QDs by hydrothermal microwave-assisted synthesis process in deionized water as solvent.
- 2- To study the effect of variation of x (x= 0.1 to 0.9) of  $Zn_xCd_{1-x}S$  quantum dot in particle size, size distribution, morphology, and optical properties.
- 3- To investigate the influence of capping agents on synthesis and the growth process of  $Zn_{0.9}Cd_{0.1}S$  semiconductor nanoparticles, and their physical and optical properties.

### 1.4 Scope of study

This work will deal with the important understanding of the synthetic conditions and the surface modification process relation of chalcogenide-based semiconductors. In particular, this thesis prepares and characterizes the  $Zn_xCd_{1-x}S$  semiconductor QDs to examine their interesting properties and potential for extensive research. The microwave-assisted synthesis method is used to make the semiconductor QDs. Microwave irradiation of precursors decreases the time of reaction from days to minutes and produces smaller particles with a narrow particle size distribution and high purity. With a knowledge of nucleation and growth process, the tuning the size and controlling the shape, structure, and optical properties can be studied. The production of the best quality materials is carried out through selectively isolating

the materials that actively contribute to the most nucleation events followed by efficient growth of the nanoparticles through the use of microwave irradiation. The experimental condition such as concentration of precursors, and the type and concentration of capping agents has also influence in quality of nanoparticles. This thesis is divided into two sections. In the first section the  $Zn_xCd_{1-x}S$  with different values of  $x$  (0.1, 0.3, 0.5, 0.7, and 0.9) was synthesized through the reaction of zinc chloride, cadmium chloride, and sodium sulfide in deionized water as solvent with the aid of microwave radiation as a heating source in order to study the effect of concentration of precursors on the size distribution, optical properties, and morphology of nanoparticles. Second section provides a synthesis process of PVP and TGA capped  $Zn_{0.9}Cd_{0.1}S$  with different concentration of stabilizer from 1% to 5% to monitor the effect of capping agents on the synthesis process, particle size, and size distribution of semiconductor QDs.

### 1.5 Thesis outline

This thesis presents a microwave-assisted hydrothermal synthesis route and characterization of ZnCdS semiconductor ternary QDs with variable concentrations of Zn as one of the precursors, and PVP, and TGA as capping agents. The outline of this thesis comes as follow:

Chapter 1 presents an introduction of this research, including the background of study, problem statement, scope, and objective of the study. Chapter 2 deals with a history of Nanoscience, quantum dot, and chalcogenide  $Zn_xCd_{1-x}S$  semiconductor nanoparticles and related literature in view of the synthesis process of nanoparticles. Chapter 3 is focused on a theory of electronic states of semiconductors and QDs, growth and nucleation process in the synthesis of nanoparticles, and microwave irradiation and its effect on materials. Chapter 4 provides the methodology of this work containing materials, experiment section, and characterization of semiconductor nanoparticles and the related methods. The major part of this thesis has come in Chapter 5 which describes the experimental results and related analysis. The summary and suggestions for future work has presented in last chapter (Chapter 6).

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